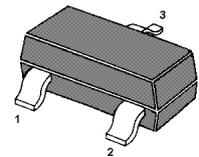
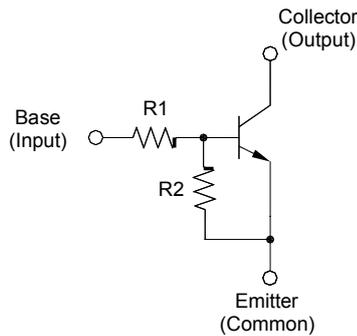


NPN Silicon Epitaxial Planar Transistor

for high current switching, interface circuit and driver circuit application.

Feature

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing Process



1. Base 2. Emitter 3. Collector
SOT-23 Plastic Package

Resistor Values

| Type | R1 (K Ω) | R2 (K Ω) |
|-------------|------------------|------------------|
| MMBTRC241SS | 1 | 1 |
| MMBTRC242SS | 2.2 | 2.2 |
| MMBTRC243SS | 4.7 | 4.7 |
| MMBTRC244SS | 10 | 10 |
| MMBTRC245SS | 1 | 10 |
| MMBTRC246SS | 2.2 | 10 |

Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

| Parameter | | Symbol | Value | Unit |
|---------------------------|-------------|-----------|---------------|------------------|
| Output Voltage | | V_o | 50 | V |
| Input Voltage | MMBTRC241SS | V_i | 10, -10 | V |
| | MMBTRC242SS | | 12, -10 | |
| | MMBTRC243SS | | 20, -10 | |
| | MMBTRC244SS | | 30, -10 | |
| | MMBTRC245SS | | 10, -5 | |
| | MMBTRC246SS | | 12, -6 | |
| Output Current | | I_o | 300 | mA |
| Total Power Dissipation | | P_{tot} | 200 | mW |
| Junction Temperature | | T_j | 150 | $^\circ\text{C}$ |
| Storage Temperature Range | | T_{stg} | - 55 to + 150 | $^\circ\text{C}$ |

Characteristics at $T_a = 25\text{ °C}$

| Parameter | Symbol | Min. | Typ. | Max. | Unit |
|---|---------------------|--------------------------|------|------|---------------|
| DC Current Gain at $V_O = 5\text{ V}$, $I_O = 50\text{ mA}$ | G _I | MMBTRC241SS 33 | - | - | - |
| | | MMBTRC242SS 39 | - | - | - |
| | | MMBTRC243SS 47 | - | - | - |
| | | MMBTRC244SS 56 | - | - | - |
| | | MMBTRC245SS 56 | - | - | - |
| | | MMBTRC246SS 56 | - | - | - |
| Output Cutoff Current at $V_O = 30\text{ V}$ | $I_{O(OFF)}$ | - | - | 10 | μA |
| Input Current at $V_I = 5\text{ V}$ | I _I | MMBTRC241SS - | - | 7.2 | mA |
| | | MMBTRC242SS - | - | 3.8 | |
| | | MMBTRC243SS - | - | 1.8 | |
| | | MMBTRC244SS - | - | 0.88 | |
| | | MMBTRC245SS - | - | 7.2 | |
| | | MMBTRC246SS - | - | 3.6 | |
| Output Voltage at $I_O = 10\text{ mA}$, $I_I = 0.5\text{ mA}$ | $V_{O(ON)}$ | - | - | 0.3 | V |
| Input Voltage (ON) at $V_O = 0.3\text{ V}$, $I_O = 20\text{ mA}$ | $V_{I(ON)}$ | MMBTRC241SS - | - | 3 | V |
| | | MMBTRC242SS - | - | 3 | |
| | | MMBTRC243SS - | - | 3 | |
| | | MMBTRC244SS - | - | 3 | |
| | | MMBTRC245SS - | - | 3 | |
| | | MMBTRC246SS - | - | 2 | |
| Input Voltage (OFF) at $V_O = 5\text{ V}$, $I_O = 0.1\text{ mA}$ | $-V_{I(OFF)}$ | MMBTRC241SS~244SS 0.5 | - | - | V |
| | | MMBTRC245SS~246SS 0.3 | - | - | |
| Transition Frequency at $V_O = 10\text{ V}$, $I_O = 5\text{ mA}$, $f = 100\text{ MHz}$ | f_T ¹⁾ | - | 200 | - | MHz |

1) Characteristic of transistor only.

